

Date: - 13 June 06

Data Sheet Issue:- 2

Rectifier Diode Types W0642WC160 to W0642WC240

Old Type No.: SW16-24CXC380

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	1600-2400	٧
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	1700-2500	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
I _{F(AV)M}	Maximum average forward current, T _{sink} =55°C, (note 2)	642	Α
$I_{F(AV)M}$	Maximum average forward current. T _{sink} =100°C, (note 2)	477	Α
$I_{F(AV)M}$	Maximum average forward current. T _{sink} =100°C, (note 3)	291	Α
I _{F(RMS)}	Nominal RMS forward current, T _{sink} =25°C, (note 2)	1157	Α
I _{F(d.c.)}	D.C. forward current, T _{sink} =25°C, (note 4)	997	Α
I _{FSM}	Peak non-repetitive surge t _p =10ms, V _m =60%V _{RRM} , (note 5)	5500	Α
I _{FSM2}	Peak non-repetitive surge t _p =10ms, V _m ≤10V, (note 5)	6050	Α
l ² t	I²t capacity for fusing t _p =10ms, V _m =60%V _{RRM} , (note 5)	151×10³	A^2s
l ² t	I²t capacity for fusing t _p =10ms, V _m ≤10V, (note 5)	183×10 ³	A^2s
T _{j op}	Operating temperature range	-40 to +180	°C
T _{stg}	Storage temperature range	-40 to +200	°C

Notes:

- 1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, 190°C T_i initial.



Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V_{FM}	Maximum peak forward voltage	-	-	2.10	I _{TM} =1500A	V
V_{FM}	Maximum peak forward voltage	-	-	2.37	I _{TM} =1900A	
V_{T0}	Threshold voltage	-	-	0.99		V
r_{T}	Slope resistance	-	-	0.74		mΩ
I _{RRM}	Peak reverse current	-	-	15	Rated V _{RRM}	mA
I _{RRM}	Peak reverse current	-	-	15	Rated V _{RRM} , T _j =25°C	mA
Q_{rr}	Recovered charge	-	1000	-		μC
Q_{ra}	Recovered charge, 50% Chord	-	525	800		μC
I _{rm}	Reverse recovery current	-	70	-	I_{TM} =500A, t_p =500 μ s, di/dt=10A/ μ s, V _r =50V	Α
t _{rr}	Reverse recovery time	-	15	-		μs
0	The word we sister as it westing to be established	-	-	0.09	Double side cooled	K/W
R_{thJK}	Thermal resistance, junction to heatsink	-	-	0.18	Single side cooled	K/W
F	Mounting force	3.3	-	5.5	Note 2	kN
W_t	Weight		70			g

Notes:-

- 1) Unless otherwise indicated T_j=190°C.
- 2) For other clamp forces, please consult factory



Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V _{DRM} V _{DSM} V _{RRM} V	V _{RSM} V	V _D V _R DC V
16	1600	1700	1050
18	1800	1900	1150
20	2000	2100	1250
22	2200	2300	1350
24	2400	2500	1450

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_i below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{{V_{T0}}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T} \qquad \text{and:} \qquad W_{AV} = \frac{\Delta T}{R_{th}} \\ \Delta T = T_{j \max} - T_K$$

Where $V_{T0}=1.07V$, $r_T=0.74m\Omega$,

 $R_{\it th}$ = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance					
Conduction Angle 6 Phase (60°) 3 Phase (120°) ½ Wave (180°) d.c.					
Square wave Double Side Cooled	0.10258	0.09759	0.09519	0.09092	
Square wave Single Side Cooled	0.21094	0.20665	0.20388	0.19887	
Sine wave Double Side Cooled	0.09589	0.09352	0.09138		
Sine wave Single Side Cooled	0.20761	0.20212	0.20013		

Form Factors					
Conduction Angle 6 Phase (60°) 3 Phase (120°) ½ Wave (180°) d.c.					
Square wave	2.449	1.732	1.414	1	
Sine wave	2.778	1.879	1.57		



5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F, on page 6 is represented in two ways;

- (i) the well established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	190°C Coefficients
Α	0.990043834	-0.107758622
В	-0.01613183	0.2279921
С	2.13863×10 ⁻⁴	6.45812×10 ⁻³
D	0.02120683	-0.01105906

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

Where p = 1 to n, n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

 r_{t} = Thermal resistance at time t.

 r_p = Amplitude of p_{th} term.

 τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Single Side Cooled						
Term	Term 1 2 3 4 5					
rp	0.1359	0.01281	0.04058	7.41208×10 ⁻³	2.15859×10 ⁻³	
$ au_{\mathcal{P}}$	2.28974	1.21792	0.17167	0.02534	2.7968×10 ⁻³	

D.C. Double Side Cooled						
Term 1 2 3 4						
rp	0.05189	0.02567	0.01199	1.36098×10 ⁻³		
$ au_{\mathcal{P}}$	0.39897	0.16272	0.04052	8.55833×10 ⁻³		

6.0 Reverse recovery ratings

(i) Q_{ra} is based on 50% I_{rm} chord as shown in Fig. 1

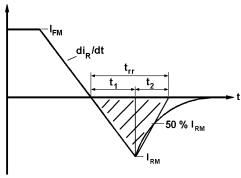


Fig. 1

(ii) Q_{rr} is based on a 150µs integration time i.e.

$$Q_{rr} = \int_{0}^{150\,\mu s} i_{rr}.dt$$

(iii)
$$K Factor = \frac{t_1}{t_2}$$

Curves

Figure 1 - Forward characteristics of Limit device

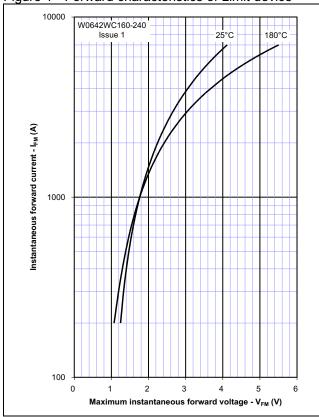
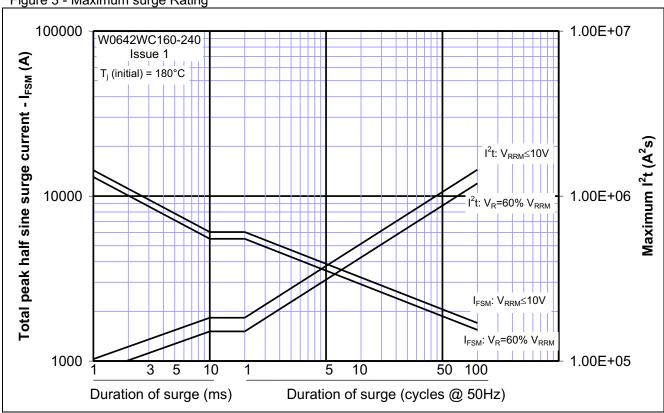


Figure 3 - Maximum surge Rating



0.0001

0.001

0.01

0.1

Time (s)

10

100

Figure 4 - Total recovered charge, Q_{rr}

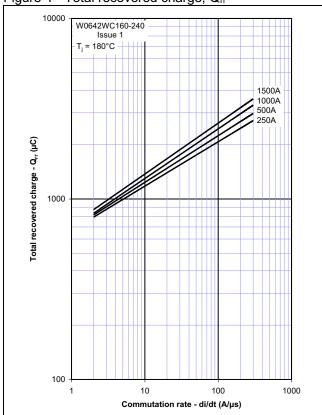


Figure 5 - Recovered charge, Q_{ra} (50% chord)

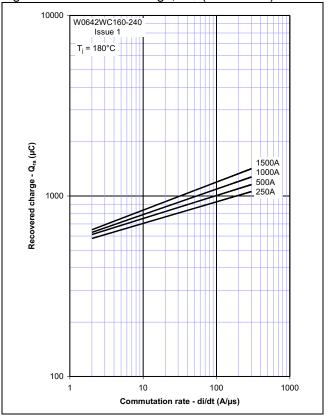


Figure 6 - Peak reverse recovery current, Irm

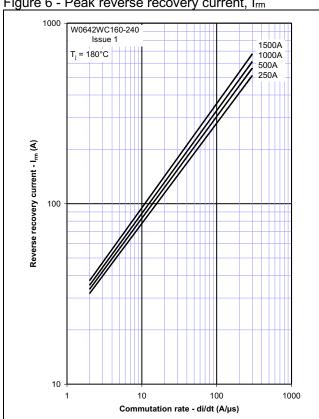


Figure 7 - Maximum recovery time, t_{rr} (50% chord)

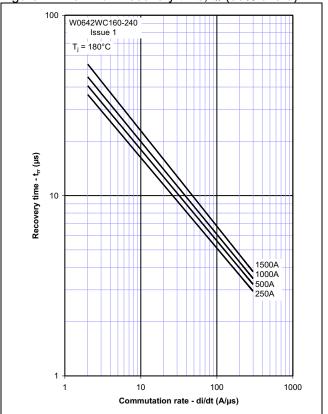


Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

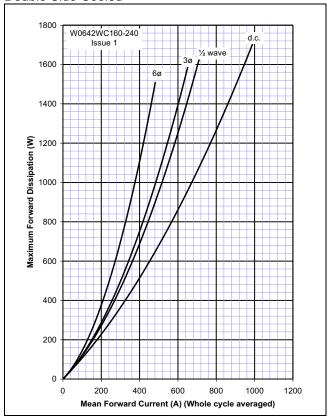


Figure 10 – Forward current vs. Power dissipation – Single Side Cooled

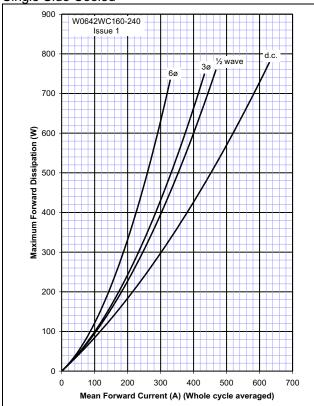


Figure 9 – Forward current vs. Heatsink temperature - Double Side Cooled

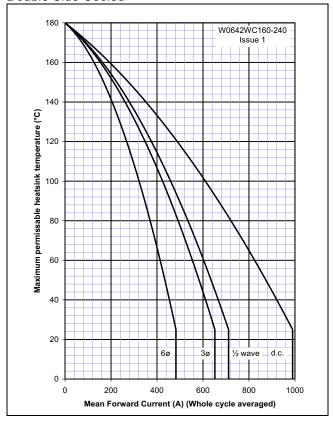
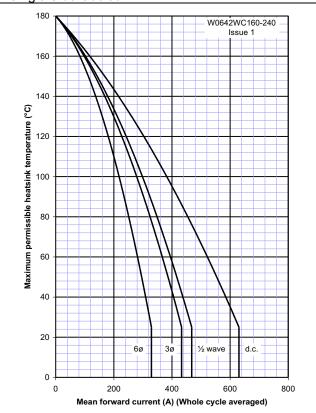
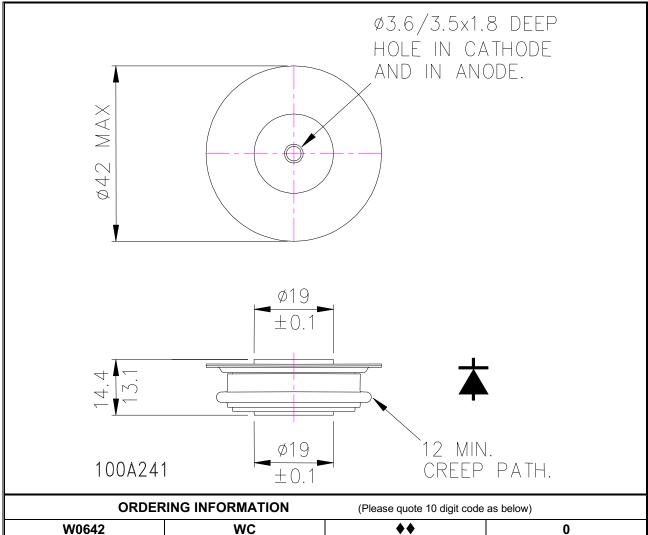


Figure 11 – Forward current vs. Heatsink temperature – Single Side Cooled



Outline Drawing & Ordering Information



W0642	WC	**	0
Fixed Type Code	Fixed outline code	Voltage code V _{DRM} /100 16-24	Fixed code

Order code: W0642WC220 - 2200V V_{RRM}, 14.4mm clamp height capsule.

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